



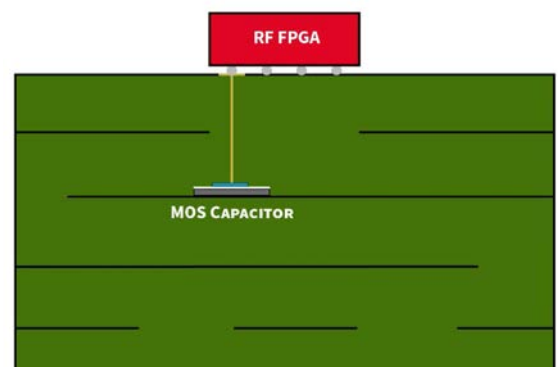
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EMBEDDABLE SOLUTIONS

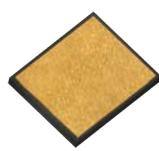
GENERAL OVERVIEW

As RF systems begin to push into higher frequencies within smaller form factors, there has been a recent shift in the industry towards embedding passive components. By integrating ultra-thin capacitors into the printed circuit board, designers will see increased board space, improved RF performance, and significantly reduced trace inductance.

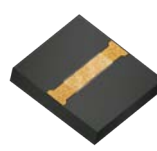
For seamless embedding in RF applications, KYOCERA AVX offers a wide range of single layer capacitors: SLC, MOS, MIS, MIM, and more in development.



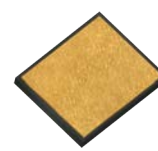
SLC



MOS/MIS
Capacitor



MIM
Capacitor



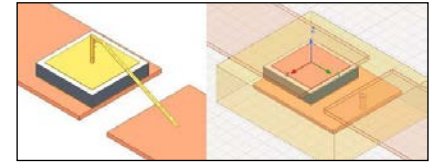
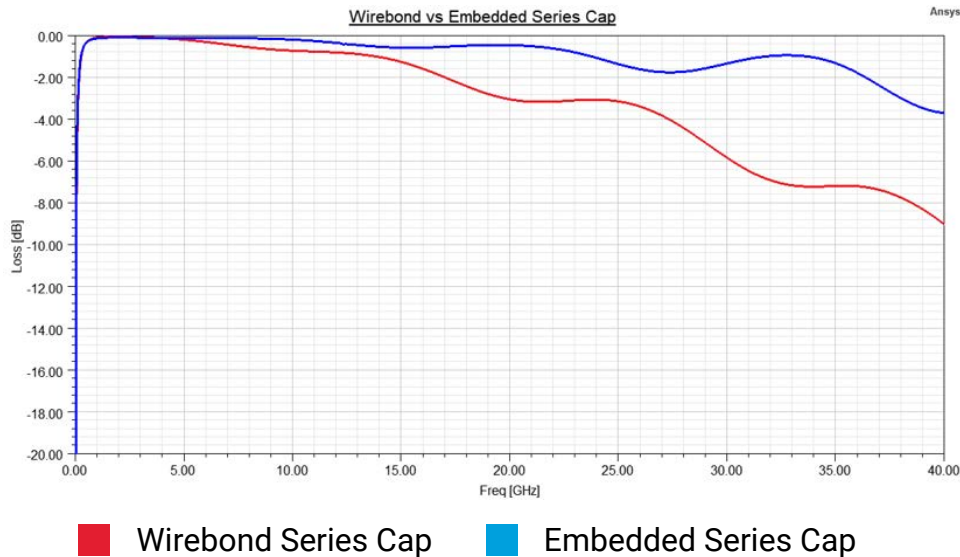
Single Layer
Resistance Capacitor

EMBEDDING MLCC'S VS SLC'S

	Embedded MLCC	Embedded SLC and MOS Capacitors
Typical RF Applications	MLCC's are not recommended for RF embedding use	Coupling, Impedance Matching, High-Speed Decoupling
Profile	Thick - Z dimension makes it difficult to use in non-surface mount situations	Ultra Thin - Z dimension allows for optimal embeddable design
Q-Factor	Moderate - Adequate Q in low to mid frequencies and falls off near SRF	High - Improved frequency response and RF performance Tunable - Resistance Capacitor can replace an inline resistor in cases that require it
CTE Mismatch Risk	High - The low CTE of ceramic can cause cracks and delamination on the MLCC over time	Low - SLCs can be customized for embedding with better material matching
Design Flexibility	Low - 2 termination on MLCC's limit versatility in layouts	High - Components can be made rectangular or square to match design needs. Large surface area available for via placement.

WIREBOND VS. EMBEDDED-MODELED PERFORMANCE

MOS Cap Performance Modeled in Ansys HFSS



Left: 10pF MOS capacitor on Rogers 4350 test board with wirebond connection.

Right: 10pF MOS capacitor embedded in epoxy filled Rogers 4350 test board with via to transmission line.

Wirebond performance degrades at 5GHz.

Embedded method allows cap performance to extend beyond 20GHz with minimal loss.

PRODUCT LINEUP

MOS Capacitor		
	Dielectric	SiO ₂
	Frequency	≤100 GHz
	Capacitance	1 - 1,200 pF
	Voltage	25 - 200 V _{DC}
	Thickness	5 - 10 MIL

MIS Capacitor		
	Dielectric	SiON
	Frequency	≤100 GHz
	Capacitance	1 - 1,800 pF
	Voltage	25 - 200 V _{DC}
	Thickness	5 - 10 MIL

MIM Capacitor		
	Substrate	Alumina, Quartz
	Frequency	≤100 GHz
	Capacitance	1 - 15 pF
	Voltage	100 V _{DC}
	Thickness	5, 10 MIL

Single Layer Ceramic Capacitor		
	Dielectric	NPO-X7R
	Frequency	≤100 GHz
	Capacitance	1.0 pF - 10 nF
	Voltage	25 - 200 V _{DC}
	Thickness	4.5 - 12 MIL

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